

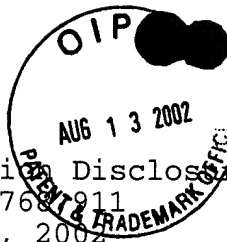
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Form PTO-1449 (Modified)	ATTY DOCKET NO. B-3962 618027-2	U.S. SERIAL NO. 09/768,911
LIST OF PATENTS AND PUBLICATIONS STATEMENT	APPLICANT(S) Lap-Wai CHOW, et al.	
	FILING DATE January 24, 2001	GROUP 2811 2827

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